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MICO	DALATION	DISC	I OSLIDE	Filing Date	March 2, 2004	
				First Named Inventor	TASHIRO	vn
STA	LEWENI B.	Y AP	PLICANI	Group Art Unit	Unassigned	
	(Use as many shee	ts as nec	essary)	Examiner Name	Unassigned	
Sheet	1	of	1	Attorney Docket Number	402991	

			U	S. PATENT DOCUMENTS		
Examiner	Examiner	U.S. Patent Docu Application or	ment Kind	Name of Patenton or Applicant	Date of	Filing Date If
Initials	Doc. No.	Patent Number	Code	Name of Patentee or Applicant	Publication	Appropriate
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Examiner Initials		Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item			
	Doc. No.	(book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number (s), publisher, city and/or country where published.	Yes	No*+	
MI	Α7	MATSUMOTO et al.; "High Power Laser Diode with Window Grown on Facets" Sharp Gihou, Vol. 50, pp. 33-36, (Sept. 1991).		X+	
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Date Considered Examiner Signature

^{*} A concise statement of relevance is being submitted in lieu of a translation. 37 CFR 1.98(a)(3).

+ An English-language equivalent/patent, or an English-language abstract, or an English-language version of the search report or action by a foreign patent office in a counterpart foreign application indicating the degree of relevance found by the foreign office is being submitted in lieu of a concise explanation of relevance under 37 CFR 1.98(a)(3).